









	<h2 style="color: red;">APTM100A13DG</h2>	
	<b>Hersteller-Teilenummer:</b>	<a href="#">APTM100A13DG</a>
	<b>Hersteller / Marke:</b>	<a href="#">Microsemi</a>
	<b>Teil der Beschreibung:</b>	MOSFET 2N-CH 1000V 65A SP6
<b>Datenblätter:</b>	 <a href="#">APTM100A13DG.pdf</a>	
<b>RoHs Status:</b>	Bleifrei / RoHS-konform	
<b>Lagerzustand:</b>	New original, 1700 pcs Stock Available.	
<b>Liefern von:</b>	Hong Kong	
<b>Versandweg:</b>	DHL/Fedex/TNT/UPS/EMS	
<p>Image may be representation. See specs for product details.</p>		

### Spezifikationen

Teilenummer	<a href="#">APTM100A13DG</a>
Hersteller	<a href="#">Microsemi</a>
Beschreibung	MOSFET 2N-CH 1000V 65A SP6
Kategorie	<a href="#">Diskrete Halbleiterprodukte &gt; Transistoren-FETs,</a>
Teilstatus	1700 pcs Stock
Serie	-
Betriebstemperatur	-40°C ~ 150°C (TJ)
Befestigungsart	Chassis Mount
Leistung - max	1250W
Verpackung / Gehäuse	SP6
Supplier Device-Gehäuse	SP6
Typ FET	2 N-Channel (Half Bridge)
FET-Merkmal	Standard
Drain-Source-Spannung (Vdss)	1000V (1kV)
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	65A
Rds On (Max) @ Id, Vgs	156 mOhm @ 32.5A, 10V
VGS (th) (Max) @ Id	5V @ 6mA
Gate Charge (Qg) (Max) @ Vgs	562nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	15200pF @ 25V
Verpackung	Bulk

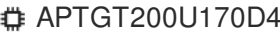

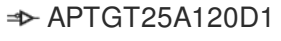
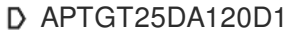
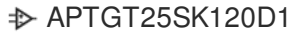

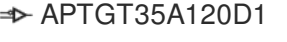
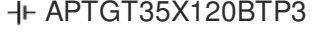


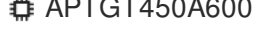
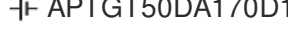
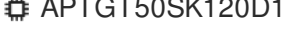
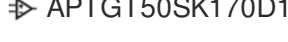
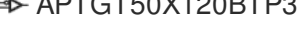
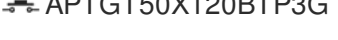



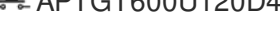
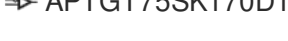
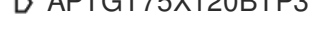
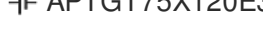
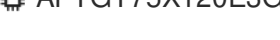
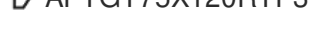
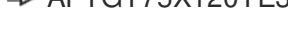
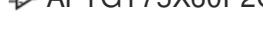

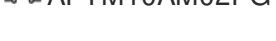
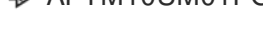


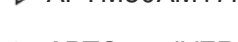



APTM100A13DG ist neu im Original, Suche APTM100A13DG Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie APTM100A13DG Microsemi mit Garantie und Vertrauen.  
Anfrage APTM100A13DG: [Info@Y-IC.com](mailto:Info@Y-IC.com)

Sie können auch interessiert sein:

 <p><b>APTLVTR</b> APEM Inc. SWITCH TACTILE SPST-NO 0.05A 12V</p>	 <p><b>APTM100A23SCTG</b> Microsemi MOSFET 2N-CH 1000V 36A SP4</p>	 <p><b>APTM08TDUM04PG</b> Microsemi MOSFET 6N-CH 75V 120A SP6-P</p>	 <p><b>APTM100A13SG</b> Microsemi MOSFET 2N-CH 1000V 65A SP6</p>
 <p><b>APTM100A12STG</b> Microsemi MOSFET 2N-CH 1000V 68A LP8W</p>	 <p><b>APTM100A23STG</b> Microsemi MOSFET 2N-CH 1000V 36A SP4</p>	 <p><b>APTM100A13SCG</b> Microsemi MOSFET 2N-CH 1000V 65A SP6</p>	 <p><b>APTM-AMBPA012-001</b> Amphenol LTW NUT M12X1.5 BRASS C3604</p>

### heiße Teile

Mehr

Contact us: [Info@Y-IC.com](mailto:Info@Y-IC.com)

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

Copyright © 2019 YIC International Co., Limited